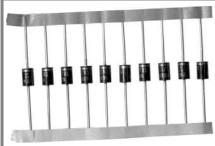
SK 3



Axial Lead Diode

Rectifier Diode

SK 3

V _{RSM}	V _{RRM}	I _{FRMS} = 6,7 A (maximu	um value for continuous o	peration)
V	V	I _{FAV} = 3 A (sin. 180; T _r = 90 °C)			
1000	1000	SK 3/10			
1200	1200	SK 3/12			
1400	1400	SK 3/14			
1600	1600	SK 3/16			
Symbol					
	Conditions			Values	Units
I _{FAV}	Conditions sin. 180; L = 10 mm	n; T _r = 85 (100) °C		Values 3,3 (2,7)	Units A
I _{FAV}		n; T _r = 85 (100) °C			
	sin. 180; L = 10 mn	· · · ·		3,3 (2,7)	А
I _{FAV}	sin. 180; L = 10 mn T _{vj} = 25 °C; 10 ms	3		3,3 (2,7) 180	A
I _{FAV} I _{FSM}	sin. 180; L = 10 mn T _{vj} = 25 °C; 10 ms T _{vj} = 150 °C; 10 ms	s 10 ms		3,3 (2,7) 180 150	A A
I _{FAV} I _{FSM}	sin. 180; L = 10 mm $T_{vj} = 25 \text{ °C}$; 10 ms $T_{vj} = 150 \text{ °C}$; 10 ms $T_{vj} = 25 \text{ °C}$; 8,3 1	s 10 ms 10 ms		3,3 (2,7) 180 150 162	A A A A²s

Features

- Reverse voltages up to 1600 V
- Taped for automatic insertion
- Available with formed leads on request
- Plastic material used carries Underwriter Laboratories flammability classification 94V-0

Typical Applications

All-purpose rectifier diodes



T_{vj} = 150 °C

T_{vj} = 150 °C

L = 10 mm

approx.

PCB 50 x 50 mm

max. 10 s; L > 9mm

1500 diodes per reel

T_{vj} = 150 °C; V_{RD} = V_{RRM}

 T_{vj} = 150 °C; - di_F/dt = 10 A/µs; I_F = 10A

V_(TO)

 \mathbf{r}_{T}

 I_{RD}

Q_{rr}

R_{th(j-r)}

R_{th(j-a)}

T_{vj} T_{stg}

T_{sold}

 V_{isol}

а

m

Case

V

mΩ

mΑ μC

K/W

K/W

°C °C

°C

V~

m/s²

g

max. 0,85

max. 30

max. 0,6

25

18

60

- 40 ... + 150

- 40 ... + 150

250

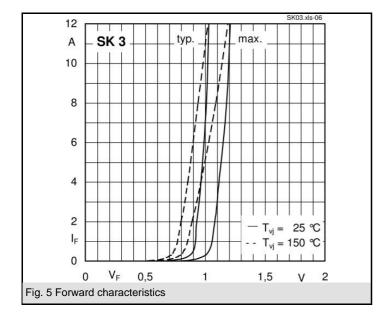
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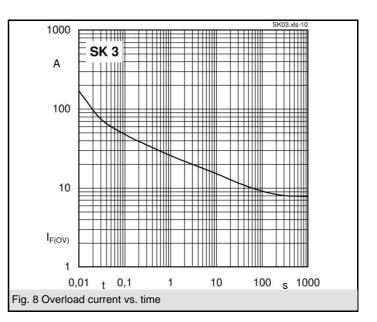
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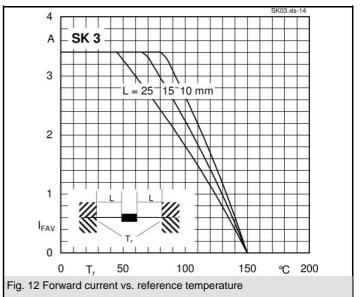
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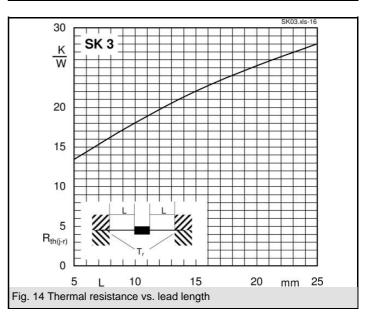
E 34

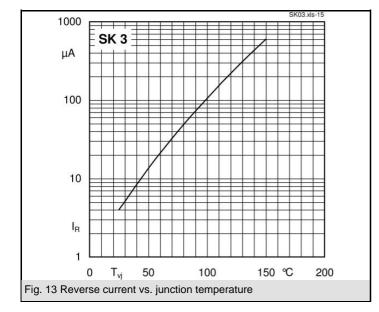
SK 3







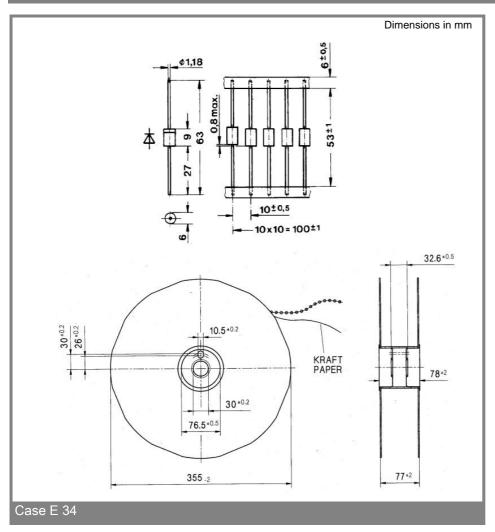




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SK 3



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